

## Description

The ICS508 is the most cost effective way to generate a high quality, high frequency CMOS clock output from a PECL clock input.

The ICS508 has separate VDD supplies for the PECL input buffer and the output buffer, allowing different voltages to be used. For example, the input clock could use a 3.3 V supply while the output operates from 2.5V.

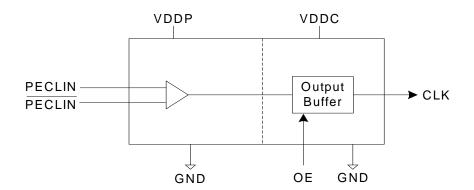
The device has an Output Enable pin that tri-states the clock output when the OE pin is taken low.

The ICS508 is a member of ICS' ClockBlocks<sup>TM</sup> family.

#### Features

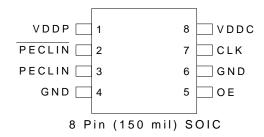
- Packaged in 8 pin SOIC or die
- Separate VDD supplies allow voltage translation
- Clock frequency of 0 250 MHz
- Duty cycle of 45/55
- Operating voltages of 2.375 to 5.5V
- Tri-state output for board level testing
- 24mA output drive capability
- Industrial temperature version available
- Advanced, low power, sub-micron CMOS process

### **Block Diagram**





### **Pin Assignment**



### **Pin Descriptions**

| Pin<br>Number | Pin<br>Name | Pin<br>Type | Pin Description  |
|---------------|-------------|-------------|--|
| 1             | VDDP        | Output      | Connect to 3.3V or 5V. Supplies PECL input buffer.                       |
| 2             | PECLIN      | Input       | Complementary PECL clock input.  |
| 3             | PECLIN      | Input       | PECL clock input.  |
| 4             | GND         | Power       | Connect to ground.   |
| 5             | OE          | Input       | Output enable. Tri-states CLK output when low. Internal pull-up to VDDC. |
| 6             | GND         | Power       | Connect to ground.   |
| 7             | CLK         | Output      | Clock output.  |
| 8             | VDDC        | Power       | Connect to 2.5V, or 3.3V, or 5V. Supplies output buffer and OE pin.      |

### **External Components**

The ICS508 requires two  $0.01\mu$ F decoupling capacitors to be connected between VDDP and GND and between VDDC and GND. They must be connected close to the ICS508 to minimize lead inductance. A 33 $\Omega$  series terminating resistor can be used next to the CLK pin.

2



### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS508. These ratings, which are standard values for ICS commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

| Item                                    | Rating             |
|---|--------------------|
| Supply Voltage, VDDP and VDDC           | 7V                 |
| PECL Inputs                             | -0.5V to VDDP+0.5V |
| Clock Output and OE Pin                 | -0.5V to VDDC+0.5V |
| Ambient Operating Temperature, ICS508   | 0 to +70°C         |
| Ambient Operating Temperature, ICS508MI | -40 to +85°C       |
| Storage Temperature                     | -65 to +150°C      |
| Soldering Temperature                   | 260°C              |

# **Recommended Operation Conditions**

| Parameter   | Min.            | Тур. | Max.  | Units |
|---|-----------------|------|-------|-------|
| Ambient Operating Temperature, ICS508M            | 0               |      | +70   | °C    |
| Ambient Operating Temperature, ICS508MI           | -40             |      | +85   | °C    |
| Power Supply Voltage (measured in respect to GND) | +3.15           |      | +3.45 | V     |
| Reference crystal parameters                      | Refer to page 3 |      |       | •     |

### **DC Electrical Characteristics**

VDDP = VDDC =3.3V ±5%, Ambient temperature 0 to +70°C, unless stated otherwise

| Parameter                  | Symbol          | Conditions            | Min.       | Тур. | Max.       | Units |
|----------------------------|-----------------|-----------------------|------------|------|------------|-------|
| Operating Voltage          | VDD             | VDDP                  | 3          |      | 5.5        | V     |
|                            | VDD             | VDDC                  | 2.375      |      | 5.5        | V     |
| Peak to Peak Input Voltage |                 | PECLIN                | 0.3        |      | 1          | V     |
| Common Mode Range          |                 | PECLIN<br>VDDP = 5V   | VDDP - 3.7 |      | VDDP - 0.6 | V     |
|                            |                 | PECLIN<br>VDDP = 3.3V | VDDP - 2.0 |      | VDDP - 0.6 | V     |
| Input High Voltage         | V <sub>IH</sub> | OE only               | 2          |      | VDDC       | V     |
| Input Low Voltage          | V <sub>IL</sub> | OE only               |            |      | 0.8        | V     |

MDS 508 D



| Parameter                | Symbol          | Conditions                  | Min.       | Тур. | Max. | Units |
|--------------------------|-----------------|-----------------------------|------------|------|------|-------|
| Output High Voltage      | V <sub>OH</sub> | VDDC = 5V<br>IOH = -24 mA   | VDDC - 0.4 |      |      | V     |
|                          |                 | VDDC = 3.3V<br>IOH = -18 mA | VDDC - 0.4 |      |      | V     |
|                          |                 | VDDC = 2.5V<br>IOH = -8 mA  | VDDC - 0.4 |      |      | V     |
| Output Low Voltage       | V <sub>OL</sub> | VDDC = 5V<br>IOL = 24 mA    |            |      | 0.4  | V     |
|                          |                 | VDDC = 3.3V<br>IOL = 18 mA  |            |      | 0.4  | V     |
|                          |                 | VDDC = 2.5V<br>IOL = 8 mA   |            |      | 0.4  | V     |
| On Chip Pull-up Resistor | R <sub>PU</sub> | OE                          |            | 250  |      | kΩ    |
| Operating Supply Current | IDDP            | 100 MHz, no load            |            | 1.5  |      | mA    |
|                          | IDDC            | 100 MHz, no load            |            | 8    |      | mA    |

Note 1: VDDP must always be greater than or equal to VDDC

# **AC Electrical Characteristics**

| $VDDP = VDDC = 3.3V \pm 5\%$ | Ambient Temperature 0 to +70° C, unless stated otherwise |
|------------------------------|--|
|------------------------------|--|

| Parameter                              | Symbol          | Conditions                | Min. | Тур. | Max. | Units |
|--|-----------------|---------------------------|------|------|------|-------|
| Input Frequency                        | f <sub>IN</sub> |                           | 0    |      | 250  | MHz   |
| Output Clock Rise Time                 |                 | 0.8V to 2.0V, VDDC = 5V   |      | 0.4  |      | ns    |
|  |                 | 0.8V to 2.0V, VDDC = 3.3V |      | 0.6  |      | ns    |
|  |                 | 0.8V to 2.0V, VDDC = 2.5V |      | 1    |      | ns    |
| Output Clock Fall Time                 |                 | 2.0V to 0.8V, VDDC = 5V   |      | 0.4  |      | ns    |
|  |                 | 2.0V to 0.8V, VDDC = 5V   |      | 0.6  |      | ns    |
|  |                 | 2.0V to 0.8V, VDDC = 5V   |      | 1    |      | ns    |
| Output Enable Time                     |                 | OE high to output on      |      | 7    | 20   | ns    |
| Output Disable Time                    |                 | OE low to tri-state       |      | 7    | 20   | ns    |
| Propagation Delay                      |                 | VDDP = 5V, VDDC = 5V      |      | 4    | 6    | ns    |
|  |                 | VDDP = 5V, VDDC = 3.3V    |      | 4.5  | 7    | ns    |
|  |                 | VDDP = 5V, VDDC = 2.5V    |      | 5.5  | 9    | ns    |
|  |                 | VDDP = 3.3V, VDDC = 3.3V  |      | 4.5  | 7    | ns    |
|  |                 | VDDP = 3.3V, VDDC = 2.5V  |      | 5.5  | 9    | ns    |
| Output Clock Duty Cycle<br>0 - 100 MHz |                 | Any VDD combination       | 45   |      | 55   | %     |

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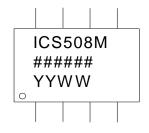


| Parameter               | Symbol | Conditions               | Min. | Тур. | Max. | Units |
|-------------------------|--------|--------------------------|------|------|------|-------|
| Output Clock Duty Cycle |        | VDDP = 5V, VDDC = 5V     | 45   |      | 55   | %     |
| 100 - 166 MHz           |        | VDDP = 5V, VDDC = 3.3V   | 45   |      | 55   | %     |
|                         |        | VDDP = 5V, VDDC = 2.5V   | 40   |      | 60   | %     |
|                         |        | VDDP = 3.3V, VDDC = 3.3V | 40   |      | 60   | %     |
|                         |        | VDDP = 3.3V, VDDC = 2.5V | 45   |      | 55   | %     |
| Output Clock Duty Cycle |        | VDDP = 5V, VDDC = 5V     | 40   |      | 60   | %     |
| 166 - 250 MHz           |        | VDDP = 5V, VDDC = 3.3V   | 40   |      | 60   | %     |
|                         |        | VDDP = 5V, VDDC = 2.5V   | 35   |      | 65   | %     |
|                         |        | VDDP = 3.3V, VDDC = 3.3V | 35   |      | 65   | %     |
|                         |        | VDDP = 3.3V, VDDC = 2.5V | 40   |      | 60   | %     |

# **Thermal Characteristics**

| Parameter                           | Symbol        | Conditions     | Min. | Тур. | Max. | Units |
|-------------------------------------|---------------|----------------|------|------|------|-------|
| Thermal Resistance Junction to      | $\theta_{JA}$ | Still air      |      | 150  |      | °C/W  |
| Ambient                             | $\theta_{JA}$ | 1 m/s air flow |      | 140  |      | °C/W  |
|                                     | $\theta_{JA}$ | 3 m/s air flow |      | 120  |      | °C/W  |
| Thermal Resistance Junction to Case | $\theta_{JC}$ |                |      | 40   |      | °C/W  |

# **Marking Diagram**



Notes:

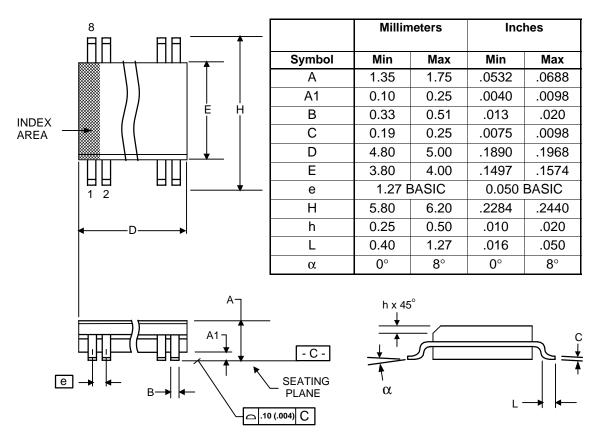
1. ###### is the lot number

2. YYWW is the last two digits of the year and the week number that the part was assembled



### Package Outline and Package Dimensions (8 pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



### **Ordering Information**

| Part / Order Number | Marking | Shipping<br>packaging       | Package     | Temperature   |
|---------------------|---------|-----------------------------|-------------|---------------|
| ICS508M             | ICS508M | Tubes                       | 8 pin SOIC  | 0 to +70° C   |
| ICS508MT            | ICS508M | Tape and Reel               | 8 pin SOIC  | 0 to +70° C   |
| ICS508MI            | ICS508I | Tubes                       | 8 pin SOIC  | -40 to +85° C |
| ICS508MIT           | ICS508I | Tape and Reel               | 8 pin SOIC  | -40 to +85° C |
| ICS508-DWF -        |         | Die on uncut, probed wafers |             | 0 to +70° C   |
| ICS508-DPK          | -       | Tested die in               | 0 to +70° C |               |

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